

# High-Current Complementary Silicon Power Transistors

... designed for use in high-power amplifier and switching circuit applications.

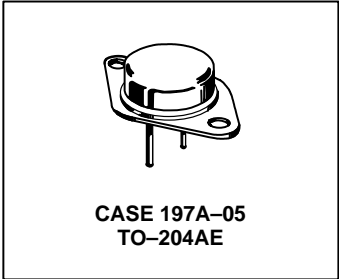
- High Current Capability –  
 $I_C$  Continuous = 50 Amperes.
- DC Current Gain –  
 $h_{FE} = 15-60 @ I_C = 25 \text{ A dc}$
- Low Collector-Emmitter Saturation Voltage –  
 $V_{CE(sat)} = 1.0 \text{ V dc (Max) @ } I_C = 25 \text{ A dc}$

**PNP  
2N5684  
NPN  
2N5686**

**50 AMPERE  
COMPLEMENTARY  
SILICON  
POWER TRANSISTORS  
60-80 VOLTS  
300 WATTS**

## MAXIMUM RATINGS (1)

Rating	Symbol	2N5684 2N5686	Unit
Collector-Emmitter Voltage	$V_{CEO}$	80	Vdc
Collector-Base Voltage	$V_{CB}$	80	Vdc
Emmitter-Base Voltage	$V_{EB}$	5.0	Vdc
Collector Current – Continuous	$I_C$	50	A dc
Base Current	$I_B$	15	A dc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	300 1.715	Watts W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-65 to +200	$^\circ\text{C}$



## THERMAL CHARACTERISTICS (1)

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$\theta_{JC}$	0.584	$^\circ\text{C/W}$

(1) Indicates JEDEC Registered Data.

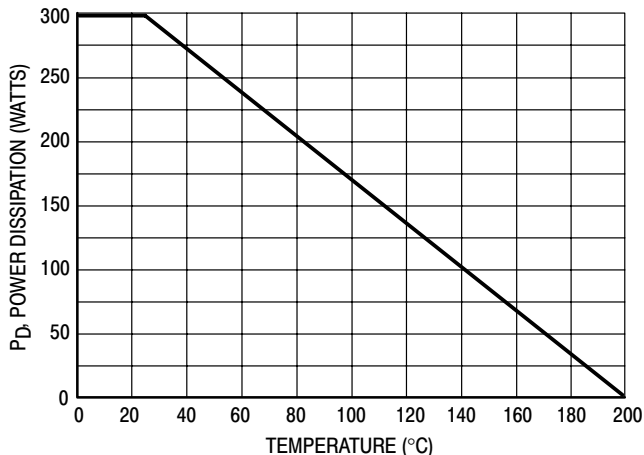


Figure 1. Power Derating

Safe Area Curves are indicated by Figure 5. All limits are applicable and must be observed.

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\*ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$  unless otherwise noted)

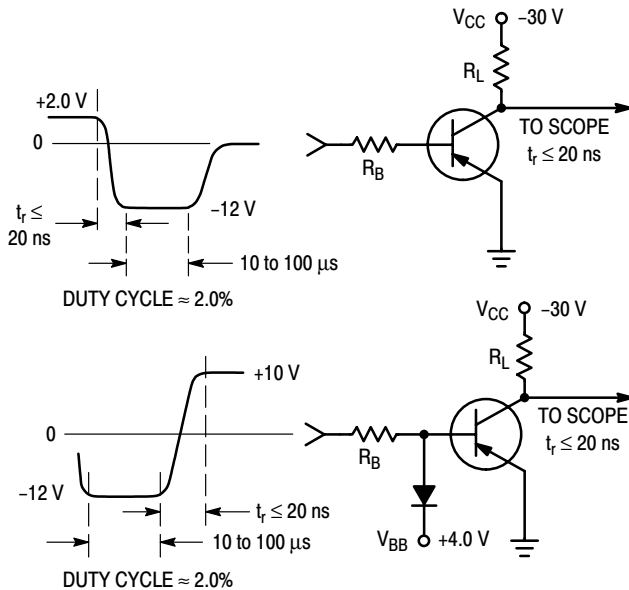
Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Collector–Emitter Sustaining Voltage (Note 2) ( $I_C = 0.2 \text{ Adc}$ , $I_B = 0$ )	$V_{CEO(sus)}$	80	–	Vdc
Collector Cutoff Current ( $V_{CE} = 40 \text{ Vdc}$ , $I_B = 0$ )	$I_{CEO}$	–	1.0	mAdc
Collector Cutoff Current ( $V_{CE} = 80 \text{ Vdc}$ , $V_{EB(off)} = 1.5 \text{ Vdc}$ ) ( $V_{CE} = 80 \text{ Vdc}$ , $V_{EB(off)} = 1.5 \text{ Vdc}$ , $T_C = 150^\circ\text{C}$ )	$I_{CEX}$	–	2.0 10	mAdc
Collector Cutoff Current ( $V_{CB} = 80 \text{ Vdc}$ , $I_E = 0$ )	$I_{CBO}$	–	2.0	mAdc
Emitter Cutoff Current ( $V_{BE} = 5.0 \text{ Vdc}$ , $I_C = 0$ )	$I_{EBO}$	–	5.0	mAdc

<b>ON CHARACTERISTICS</b>				
DC Current Gain (Note 2) ( $I_C = 25 \text{ Adc}$ , $V_{CE} = 2.0 \text{ Vdc}$ ) ( $I_C = 50 \text{ Adc}$ , $V_{CE} = 5.0 \text{ Vdc}$ )	$h_{FE}$	15 5.0	60 –	–
Collector–Emitter Saturation Voltage (Note 2) ( $I_C = 25 \text{ Adc}$ , $I_B = 2.5 \text{ Adc}$ ) ( $I_C = 50 \text{ Adc}$ , $I_B = 10 \text{ Adc}$ )	$V_{CE(sat)}$	– –	1.0 5.0	Vdc
Base–Emitter Saturation Voltage (Note 1) ( $I_C = 25 \text{ Adc}$ , $I_B = 2.5 \text{ Adc}$ )	$V_{BE(sat)}$	–	2.0	Vdc
Base–Emitter On Voltage (Note 1) ( $I_C = 25 \text{ Adc}$ , $V_{CE} = 2.0 \text{ Vdc}$ )	$V_{BE(on)}$	–	2.0	Vdc

<b>DYNAMIC CHARACTERISTICS</b>				
Current–Gain – Bandwidth Product ( $I_C = 5.0 \text{ Adc}$ , $V_{CE} = 10 \text{ Vdc}$ , $f = 1.0 \text{ MHz}$ )	$f_T$	2.0	–	MHz
Output Capacitance ( $V_{CB} = 10 \text{ Vdc}$ , $I_E = 0$ , $f = 0.1 \text{ MHz}$ )	$C_{ob}$	–	2000 1200	pF
Small–Signal Current Gain ( $I_C = 10 \text{ Adc}$ , $V_{CE} = 5.0 \text{ Vdc}$ , $f = 1.0 \text{ kHz}$ )	$h_{fe}$	15	–	

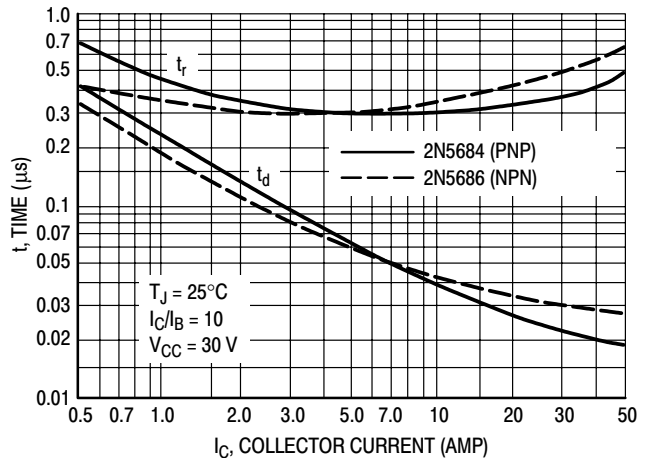
\*Indicates JEDEC Registered Data.

Note 2: Pulse Test: Pulse Width  $\leq 300 \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .



FOR CURVES OF FIGURES 3 & 6,  $R_B$  &  $R_L$  ARE VARIED.  
INPUT LEVELS ARE APPROXIMATELY AS SHOWN.  
FOR NPN CIRCUITS, REVERSE ALL POLARITIES.

**Figure 2. Switching Time Test Circuit**



**Figure 3. Turn–On Time**

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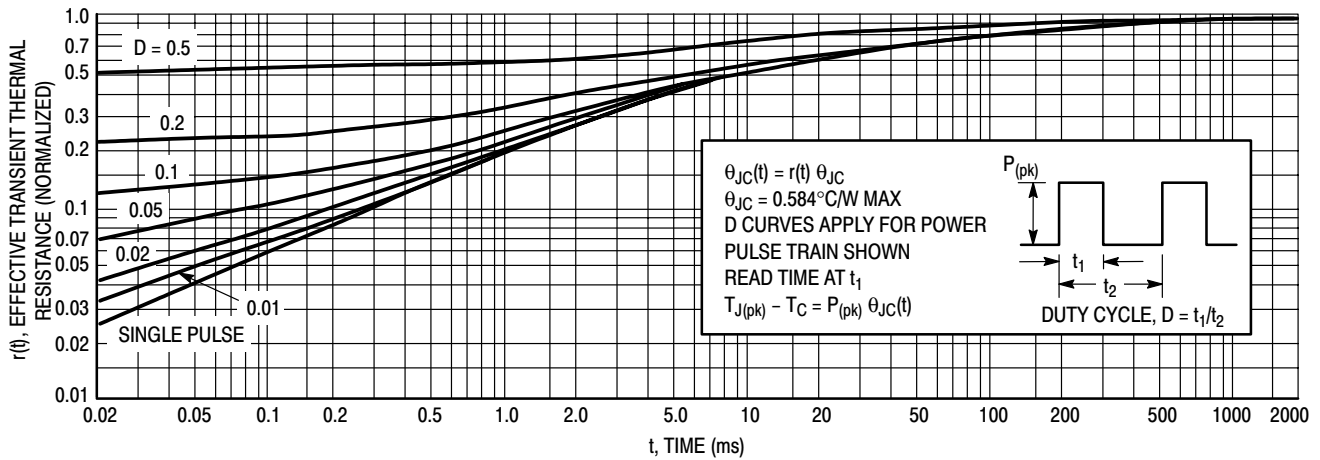


Figure 4. Thermal Response

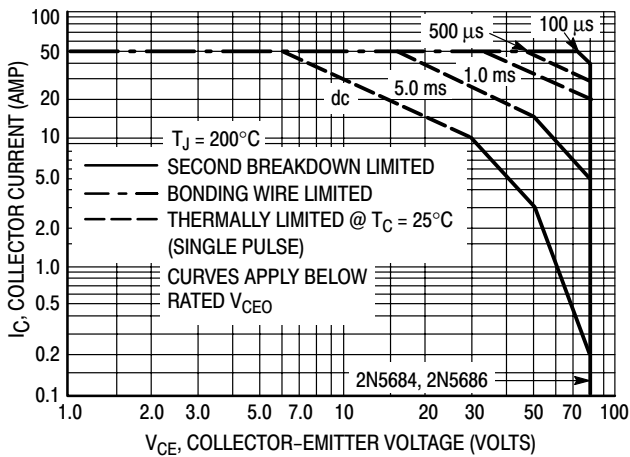


Figure 5. Active-Region Safe Operating Area

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 5 is based on  $T_{J(pk)} = 200^{\circ}\text{C}$ ;  $T_C$  is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided  $T_{J(pk)} \leq 200^{\circ}\text{C}$ .  $T_{J(pk)}$  may be calculated from the data in Figure 4. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

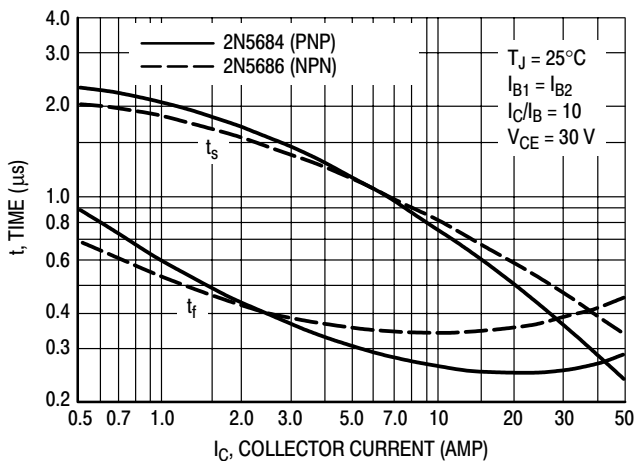


Figure 6. Turn-Off Time

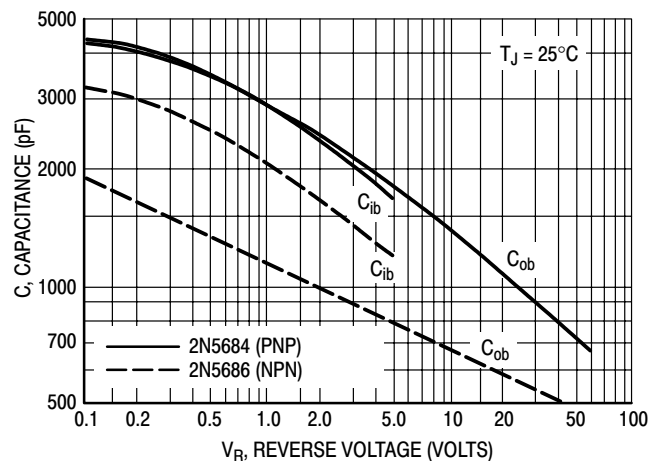
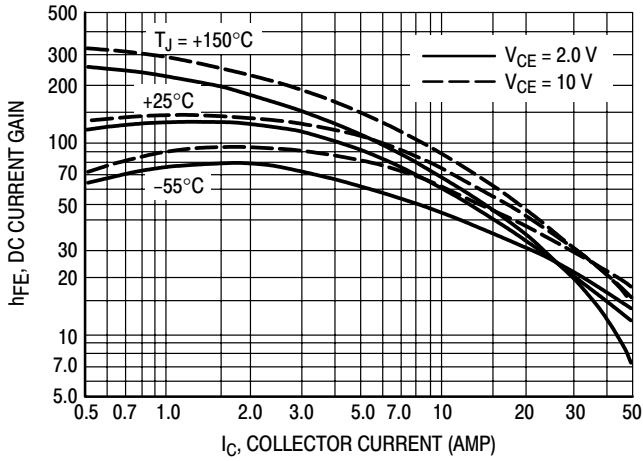


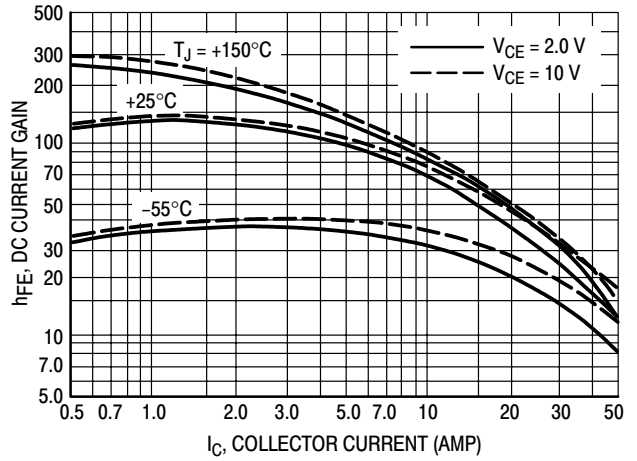
Figure 7. Capacitance

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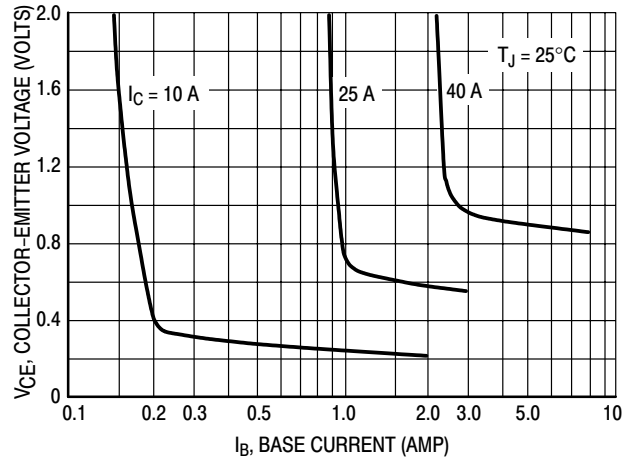
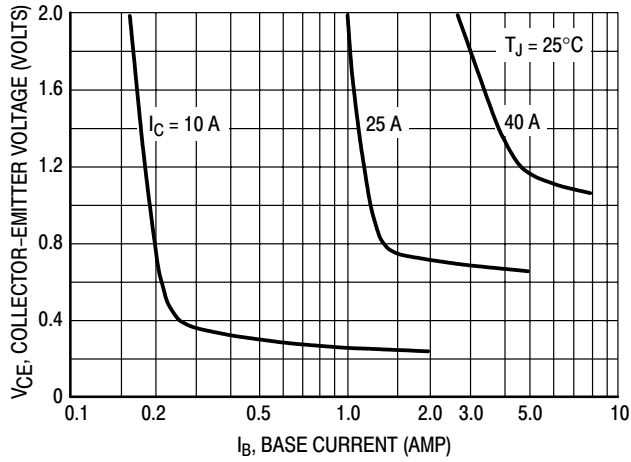
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**2N5684**



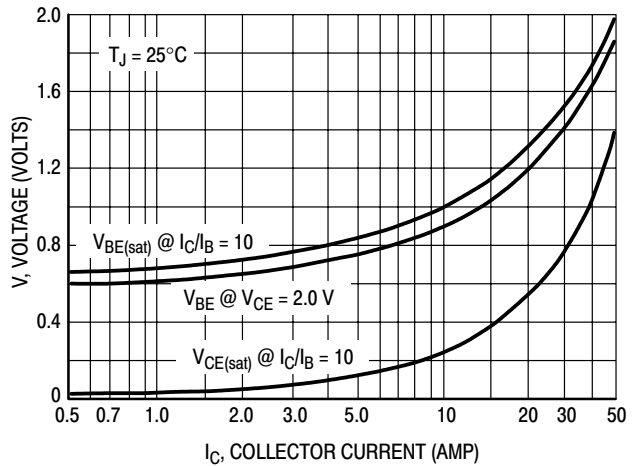
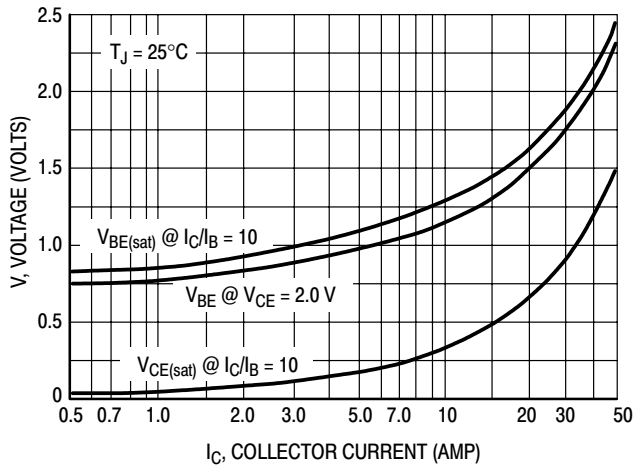
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**Figure 8. DC Current Gain**



**Figure 9. Collector Saturation Region**




**Figure 10. "On" Voltages**



## Notes

## Notes

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